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13. ABSTRACT (Maximum 200 words)

We have constructed and tested new higher-temperature ceramic (ZrO₂ and SiC) pyrolysis nozzles that can operate continuously at 1700°C for several hours. The two successful designs were used to generate intense (10¹⁶ sec⁻¹) beams of CH₃ by thermal decomposition of azomethane. We probed the pyrolysate by vacuum-UV photoionization mass spectroscopy and (mass-resolved) resonant multiphoton ionization spectroscopy and determined that the ratio of CH₃/C₂H₂ in our source is greater than 100:1. This should make it an ideal source of methyl radicals for deposition. A chamber with the pyrolysis nozzle and a separate electric discharge nozzle source of He was constructed. The two jets were directed onto a thermostatted molybdenum foil. Micro-Raman assays (NRL with Jim Butler) of deposited material showed good-quality diamond, but we could not rule out Raman signals from diamond seed crystals with which the surface was scratched. We designed an efficient synthesis for ¹³CH₃-N=N-CH₃ as a source of 50% ¹³C-enriched methyl radicals. Micro-Raman showed no evidence of ¹³C-enriched diamond, from which we conclude that we were previously seeing only the seed crystals. We are currently working on in situ probes to quantify the H^o concentration, and also trying different substrates.

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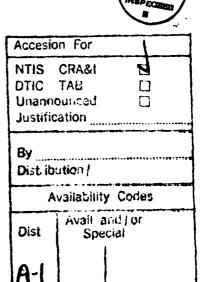
Supersonic Pyrolysis jets for Diamond Film Deposition

by

Peter Chen

Harvard University
Department of Chemistry
12 Oxford Street
Cambridge, MA 02138

June 1, 1992



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TECHNICAL REPORT FOR GRANT #N00014-91-J-1012

Supersonic Pyrolysis Jets for Diamond Film Deposition

Peter Chen
Associate Professor of Chemistry
Harvard University

May 21, 1992

Introduction.

We have developed clean supersonic nozzle sources for radicals. This project aims to apply this nozzle technology to: (1) the mechanism of diamond growth from hydrocarbon gases, and (2) selective functionalization of diamond surfaces by reaction with well-characterized gas-phase reactive intermediates. A particular emphasis in this stage of the project is growth from well-characterized methyl radical, CH₃, sources, in the absence of higher hydrocarbons, e.g. acetylene, C₂H₂. We hope to use the separation of CH₃ production from H• production from deposition to isolate and probe details of the mechanism for growth of diamond from the gas phase.

Progress for 1991-92.

The nozzle development reported in last year's report is done, giving us a reliable, reproducible source of CH_3 and other radicals. We found that pyrolysis of azomethane, CH_3 -N=N-C H_3 , at 1200° C/10 µsec in 1 atm helium carrier gas gives quantitative conversion to methyl radicals and N_2 . The 10.49 eV vacuum-UV photoionization mass spectrum showed no higher mass species. Acetylene because of its importance as a potential growth species, was probed for with resonant multiphoton ionization spectroscopy. We established our detection limits by obtaining an unambiguous spectrum with calibrated partial pressures of C_2H_2 , and then determined that, under the conditions where we could achieve CH_3 fluxes of 10^{16} sec⁻¹, the ratio of CH_3/C_2H_2 is

greater than 100:1. The absence of equilibration between CH₃ and C₂H₂ is one important way in which our thermal radical source differs from the conventional hot filament reactors.

We have constructed a deposition chamber in which there is provision for up to two separate nozzles that can be run as either pulsed or continuous flow supersonic jets. One was set up as an electric discharge nozzle for the production of H• from mixtures of H₂ in helium, and the other was set up as a pyrolysis nozzle for CH₃. We could confirm production of atomic hydrogen by rapid etching of graphite placed in the gas flow. Electrically-heated molybdenum foils at temperatures ranging from room temperature to 800°C were used as substrates, with and without scratching of the surface with 0.1-0.5 µm diamond powder. Micro-Raman spectra (performed at NRL by Jim Butler) of samples grown under a variety of conditions showed diamond on those samples which had been scratched with diamond powder. Either we could grow diamond only on a prescratched surface, or we were seeing only residual diamond powder left from the scratching. We attempted to distinguish between residual powder and new growth by examination of the crystallite size, but the results were unconvincing either way.

An unambiguous distinction could be made if we used ¹³C-labeled methyl radicals and ¹²C diamond powder because the isotope shift in the Raman spectrum is large. We developed an efficient synthesis for 50% ¹³C-enriched azomethane, with ¹³C-labeled formaldehyde (relatively inexpensive and available) as the source of the isotopic label. The synthesis of ¹³CH₃-N=N-CH₃ can be done on the gram scale for approximately \$1000/gram. The procedure is shown in Scheme I. Micro-Raman spectra of diamond grown from the isotopically-enriched methyl source showed no evidence of ¹³C incorporation. We conclude that the previous results were due to aggregates of the diamond powder used to scratch our surfaces.

Prospects for 1992-93.

There are several possibilities for the lack of diamond growth. We had used only one substrate, molybdenum, for which it is known that the sticking coefficient of CH₃ is low. We are now trying copper, silicon, and CVD diamond. For the latter, we plan to use ¹³C incorporation as the way to distinguish between the original material and any new growth. We have also completed the modifications to the chamber to allow optical access for laser-induced fluorescence probes of H* concentrations. We will now be able to optimize the atomic hydrogen production, just as we had previously optimized the CH₃ production. We have not yet explored the use of heteroatom-substituted carbenes to functionalize a diamond surface. We will try to see insertion of :CF₂, :CCl₂, and :C(SR)₂ into surface C-H bonds from the gas phase. Fluorination may impart oxidation resistance. The pendant -CHCl₂ group from dichlorocarbene insertion is convertible to a surface vinyl group by hydrolysis and Wittig reaction. This will provide the functional handle to build postulated surface structures that may reconstruct upon thermal cycling. Surface sulfur groups may improve adhesion of metal films. These possibilities have not yet been explored.

CAPTIONS

Scheme I. Synthetic scheme for the synthesis of ¹³C-labeled azomethane. All of the steps subsequent to addition to the labeled formaldehyde can be run nearly quantitatively on the gram scale.

$$O = \begin{pmatrix} CH_3 \\ *CH_3 \\ N-N \end{pmatrix} \qquad H \qquad \begin{pmatrix} *CH_3 \\ N-N \end{pmatrix} \circ 2 \ HC1 \qquad \begin{pmatrix} (1) \ NaOH \\ (2) \ HgO \end{pmatrix} \qquad \begin{pmatrix} *CH_3 \\ N-N \end{pmatrix}$$

$$CH_3 \qquad H \qquad CH_3 \qquad CH_3 \qquad CH_3$$

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